NSN 5961-01-131-3703

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-131-3703 **Inclosure Material:** Glass **Overall Length:** 4.500 inches **Terminal Length:** 0.250 inches **Overall Diameter:** 1.980 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 75.0 repetitive peak reverse voltage, peak total value and 50.0 reverse voltage, dc **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No